High power cycling capability
Low on-state and switching losses
Optimized for line frequency rectifiers
Designed for traction and industrial applications

Rectifier Diode
Type D123-320-28

Average forward current			I_{FAV}	320 A	
Repetitive peak reverse voltage			V_{RRM}	2000 ÷ 2800 V	
V_{RRM}, V	2000	2200	2400	2600	2800
Voltage code	20	22	24	26	28
T_j, °C	-60 ÷ 175				

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I_{FAV}	Average forward current	A	320 485	T_c=135 °C; Double side cooled; T_c=100 °C; Double side cooled; 180° half-sine wave; 50 Hz	
I_{FRMS}	RMS forward current	A	502	T_c=135 °C; Double side cooled; 180° half-sine wave; 50 Hz	
I_{FSM}	Surge forward current	kA	5.5 6.3	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; 50 Hz (t_p=10 ms); single pulse; V_R=0 V;
			6.0 6.9	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; 60 Hz (t_p=8.3 ms); single pulse; V_R=0 V;
I^2t	Safety factor	$A^2s\cdot10^3$	150 195	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; 50 Hz (t_p=10 ms); single pulse; V_R=0 V;
			145 195	T_j=$T_{j\,max}$ T_j=25 °C	180° half-sine wave; 60 Hz (t_p=8.3 ms); single pulse; V_R=0 V;
BLOCKING					
V_{RRM}	Repetitive peak reverse voltages	V	2000÷2800	$T_{j\,min}$< T_j <$T_{j\,max}$; 180° half-sine wave; 50 Hz;	
V_{RSM}	Non-repetitive peak reverse voltages	V	2100÷2900	$T_{j\,min}$< T_j <$T_{j\,max}$; 180° half-sine wave; 50 Hz;single pulse;	
V_R	Reverse continuous voltages	V	0.75·V_{RRM}	T_j=$T_{j\,max}$;	
THERMAL					
T_{stg}	Storage temperature	°C	-60÷50		
T_j	Operating junction temperature	°C	-60÷175		
MECHANICAL					
F	Mounting force	kN	5.0÷7.0		
a	Acceleration	m/s^2	50 100	Device unclamped Device clamped	

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions	
ON-STATE					
V_{FM}	Peak forward voltage, max	V	2.00	T_j=25 °C; I_{FM}=1005 A	
$V_{F(TO)}$	Forward threshold voltage, max	V	1.00	$T_j=T_{j\,max}$; $0.5\ \pi\ I_{FAV} < I_T < 1.5\ \pi\ I_{FAV}$	
r_T	Forward slope resistance, max	mΩ	1.000		
BLOCKING					
I_{RRM}	Repetitive peak reverse current, max	mA	35	$T_j=T_{j\,max}$; $V_R=V_{RRM}$	
THERMAL					
R_{thjc}	Thermal resistance, junction to case, max	°C/W	0.070	Direct current	Double side cooled
R_{thjc-A}			0.154		Anode side cooled
R_{thjc-K}			0.126		Cathode side cooled
R_{thck}	Thermal resistance, case to heatsink, max	°C/W	0.010	Direct current	
MECHANICAL					
w	Weight, typ	g	65		
D_s	Surface creepage distance	mm (inch)	11.74 (0.462)		
D_a	Air strike distance	mm (inch)	11.60 (0.457)		

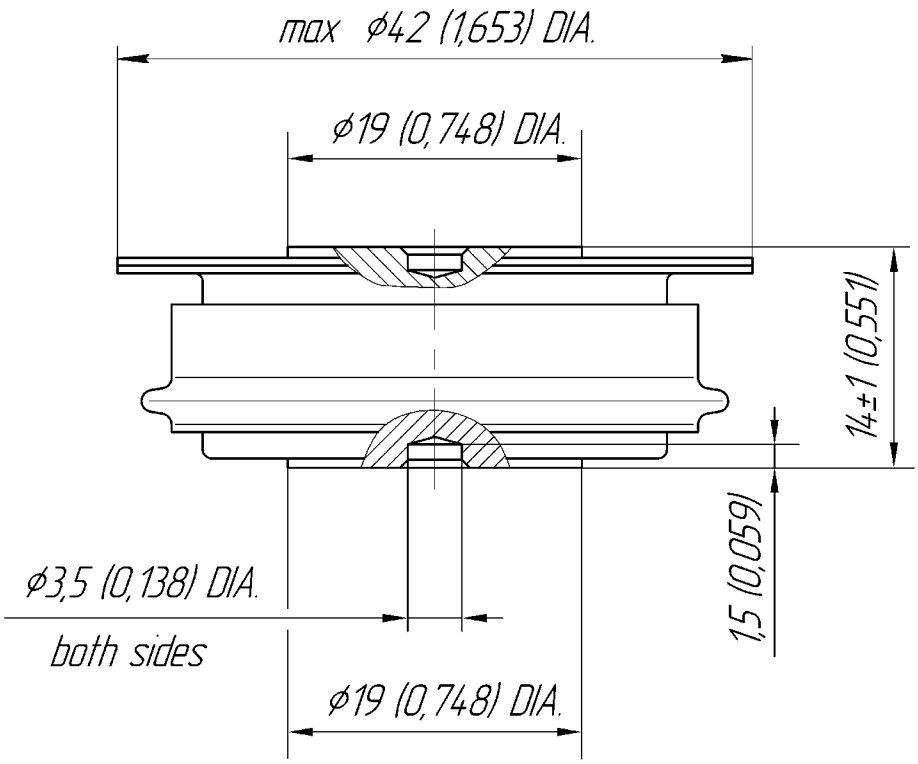
PART NUMBERING GUIDE

D	123	320	28	N
1	2	3	4	5

1. D — Rectifier Diode
2. Design version
3. Average forward current, A
4. Voltage code
5. Ambient conditions: N – normal; T – tropical

OVERALL DIMENSIONS

Package type: D.A1



All dimensions in millimeters (inches)

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